

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	4	((("5106778") or ("5612563")).PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/04/12 08:49
S2	2	"20020001905"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/12 13:05
S3	3	"09/669212"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/12 13:48
S4	9300	((inverter adj circuit) near15 transistor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/12 13:58
S5	4555	(438/763,761,758).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/04/12 14:12
S8	5	S5 and S6 and S7	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/12 14:15
S7	129163	conductive and insulator	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/12 14:15
S6	15299	carbon near10 nanotube	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/12 15:55

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S9	551	(carbon NEAR3 nanotube) NEAR5 insulat\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/12 15:56
S10	1	S9 and S5	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/12 15:57
S11	128	S9 and "257"/\$.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/12 15:58
L1	2	(US-20010023986-\$ or US-20010019279-\$).did.	US-PGPUB	OR	ON	2007/04/13 08:35
L5	256	(carbon NEAR3 nanotube) NEAR5 transistor and vertical	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/13 09:22
L4	1	L3 and L2	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/13 09:22
L3	551	(carbon NEAR3 nanotube) NEAR5 insulat\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/13 09:22
L2	4555	(438/763,761,758).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/04/13 09:22
L8	57	(carbon NEAR3 nanotube) same transistor near5 vertical	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/13 09:23

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L7	57	(carbon NEAR3 nanotube) NEAR5 transistor near5 vertical	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/13 09:23
L11	32	10 not 8	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/13 09:24
L10	89	(carbon NEAR3 nanotube) same transistor same vertical	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/13 09:24
L12	76	(carbon same nanotube same transistor same vertical) and insulat\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/13 09:26
L13	788	(gate near2 insulat\$3) and (carbon NEAR3 nanotube)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/13 09:27